Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Metal

**Overall Length:** 

1.453 inches

# Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### Do-5

**Mounting Method:** 

Threaded stud

## Overall Width Across Flats:

Between 0.667 inches and 0.687 inches

**Thread Size:** 

0.250 inches

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 reverse voltage, peak

## **Current Rating Per Characteristic:**

20.00 amperes forward current, average

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

### **Special Features:**

200 nanoseconds maximum reverse recovery time

### **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

### Unit Of Measure:

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# Demilitarization:

No

Fiig:

A110a0